

RJF0628JNS

60V, 10A Silicon N Channel Thermal FET Power Switching

R07DS1568EJ0100 Rev.1.00 Aug 09, 2024

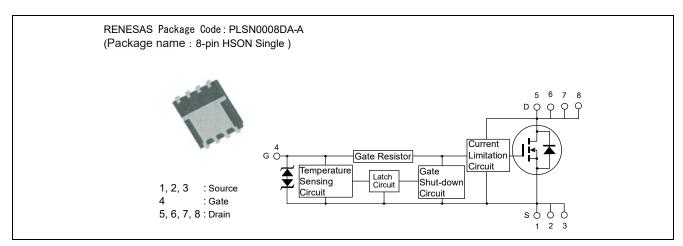
Description

This FET has the over temperature shut-down capability sensing to the junction temperature. This FET has the built-in over temperature shut-down circuit in the gate area. And this circuit operation to shut-down the gate voltage in case of high junction temperature like applying over power consumption, over current etc..

Features

- Logic level operation (4 V Gate drive).
- Built-in the over temperature shut-down circuit.
- High endurance capability against to the short circuit.
- Latch type shut down operation (need 0 voltage recovery).
- Built-in the current limitation circuit.
- Power supply voltage applies 12 V and 24 V.
- AEC-Q101 Rev-E Compliant

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to source voltage	V_{DSS}	60	V
Gate to source voltage	V _{GSS}	16	V
Gate to source voltage	V _{GSS}	-2.5	V
Drain current	I _D Note3	10	Α
Body-drain diode reverse drain current	I _{DR}	10	Α
Avalanche current	I _{AP} Note 2	10	Α
Avalanche energy	E _{AR} Note 2	30	mJ
Channel dissipation	Pch Note 1	40	W
Channel dissipation	Pch Note 4	1	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. Value at Tc = 25°C

- 2. Tch = 25°C, Rg \geq 50 Ω
- 3. It provides by the current limitation lower bound value.
- 4. When using the glass epoxy board (FR4 40 imes 40 imes 1.6 mm)

Typical Operation Characteristics

 $(Ta = 25^{\circ}C)$

Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Input voltage	VIH	3.5	_	_	V	
	VIL	_	_	1.2	V	
Input current	I _{IH1}	_	_	100	μА	Vi = 8 V, V _{DS} = 0
(Gate non shut down)	I _{IH2}	_	_	50	μА	Vi = 3.5 V, V _{DS} = 0
	I _{IL}	_	_	1	μА	Vi = 1.2 V, V _{DS} = 0
Input current	I _{IH(sd)1}	_	0.8	_	mA	Vi = 8 V, V _{DS} = 0
(Gate shut down)	I _{IH(sd)2}	_	0.35	_	mA	Vi = 3.5 V, V _{DS} = 0
Shut down temperature	Tsd	_	175	_	°C	Channel temperature
Gate operation voltage	Vop	3.5	_	12	V	
Drain current (Current limitation value)	I _{D limt}	10	_	_	А	V _{GS} = 5 V, V _{DS} = 1 V Note 5

Note; 5. Pulse test

Electrical Characteristics

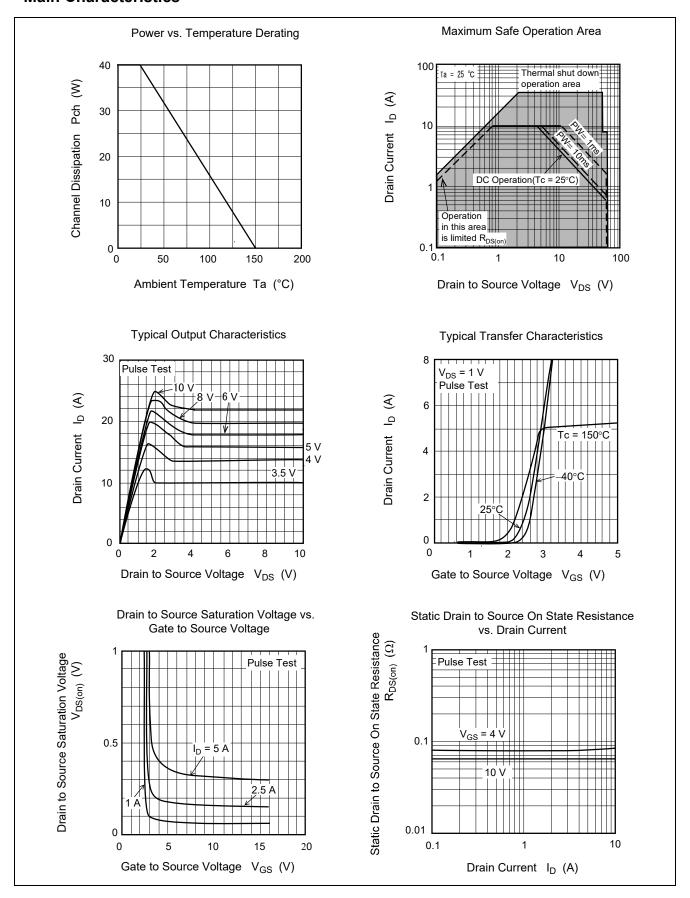
 $(Ta = 25^{\circ}C)$

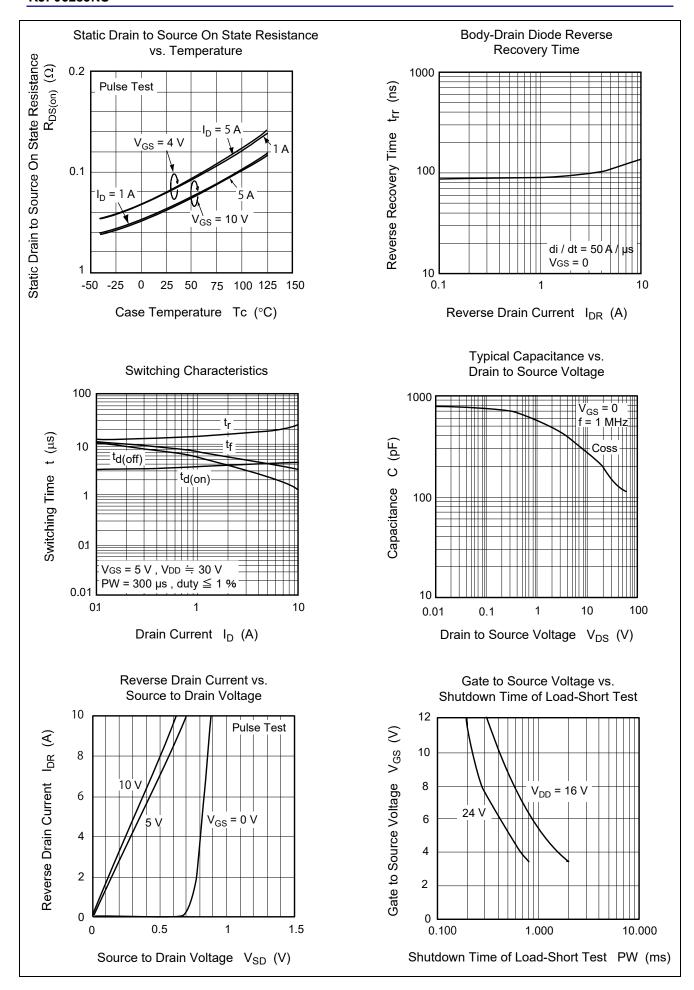
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain current	I _{D1}	_	_	17	Α	V _{GS} = 3.5 V, V _{DS} = 10 V Note 6
	I _{D2}	_	_	10	mA	V _{GS} = 1.2 V, V _{DS} = 10 V Note 6
	I _{D3}	10	_	_	Α	V _{GS} = 5 V, V _{DS} = 1 V Note 6
Drain to source breakdown voltage	V _{(BR)DSS}	60	_	_	V	I _D = 10 mA, V _{GS} = 0
Gate to source breakdown	V _{(BR)GSS}	16	_	_	V	$I_G = 800 \mu A, V_{DS} = 0$
voltage	V _{(BR)GSS}	-2.5	_	_	V	$I_G = -100 \mu A, V_{DS} = 0$
Gate to source leak current	Igss ₁	_	_	100	μΑ	V _{GS} = 8 V, V _{DS} = 0
	I _{GSS2}	_	_	50	μΑ	V _{GS} = 3.5 V, V _{DS} = 0
	Igss3	_	_	1	μА	V _{GS} = 1.2 V, V _{DS} = 0
	Igss4	_	_	-100	μА	V _{GS} = -2.4 V, V _{DS} = 0
Input current (shut down)	I _{GS(OP)1}		0.8		mA	V _{GS} = 8 V, V _{DS} = 0
	I _{GS(OP)2}		0.35		mA	$V_{GS} = 3.5 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}		_	10	μА	$V_{DS} = 60 \text{ V}, V_{GS} = 0,$
Gate to source cutoff voltage	$V_{GS(off)}$	1.1	_	2.1	V	V _{DS} = 10 V, I _D = 1 mA
Forward transfer admittance	y _{fs}	3.3	9.7	_	S	I _D = 5.0 A, V _{DS} = 1 V Note 6
Static drain to source on state	R _{DS(on)}	_	81.0	100	mΩ	I _D = 5.0 A, V _{GS} = 4 V ^{Note 6}
resistance	R _{DS(on)}	_	63.8	75	mΩ	I _D = 5.0 A, V _{GS} = 10 V ^{Note 6}
Output capacitance	Coss	_	291	_	pF	V _{DS} = 10 V, V _{GS} = 0, f = 1MHz
Turn-on delay time	t _{d(on)}	_	4.0	_	μS	$V_{GS} = 5 \text{ V}, I_{D} = 5.0 \text{ A}, R_{L} = 6 \Omega$
Rise time	t _r	_	18.6	_	μS	
Turn-off delay time	$t_{d(off)}$	_	2.2	_	μS	
Fall time	t _f	_	4.1	_	μS	
Body-drain diode forward voltage	V_{DF}	_	0.87	_	V	I _F = 10 A, V _{GS} = 0
Body-drain diode reverse recovery time Note 7	t _{rr}		134	_	ns	$I_F = 10 \text{ A}, V_{GS} = 0$ $di_F/dt = 50 \text{ A}/\mu\text{s}$
Over load shut down	t _{os1}	_	1.1	_	ms	V _{GS} = 5 V, V _{DD} = 16 V
operation time Note 7	t _{os2}	_	0.57		ms	V _{GS} = 5 V, V _{DD} = 24 V

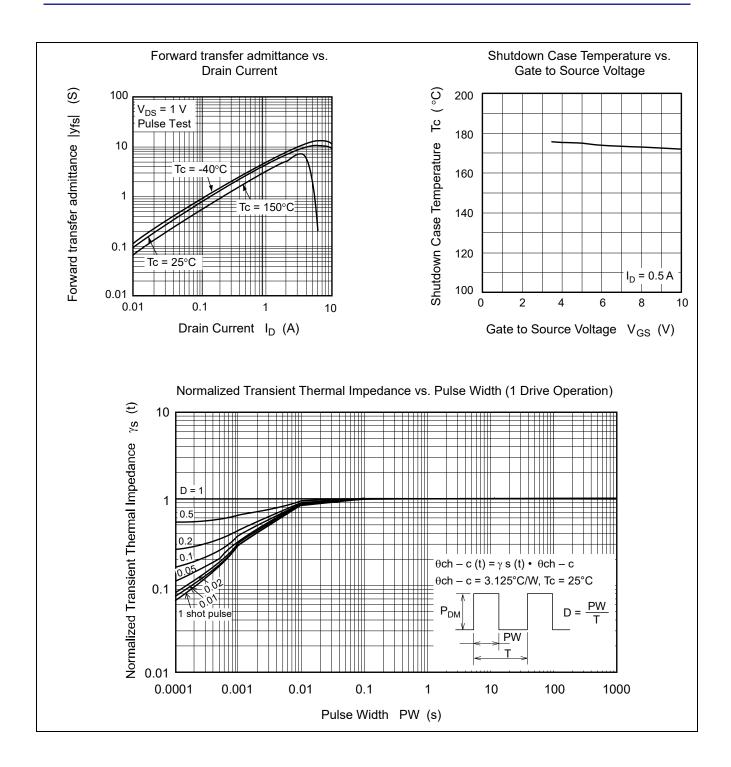
Notes: 6. Pulse test

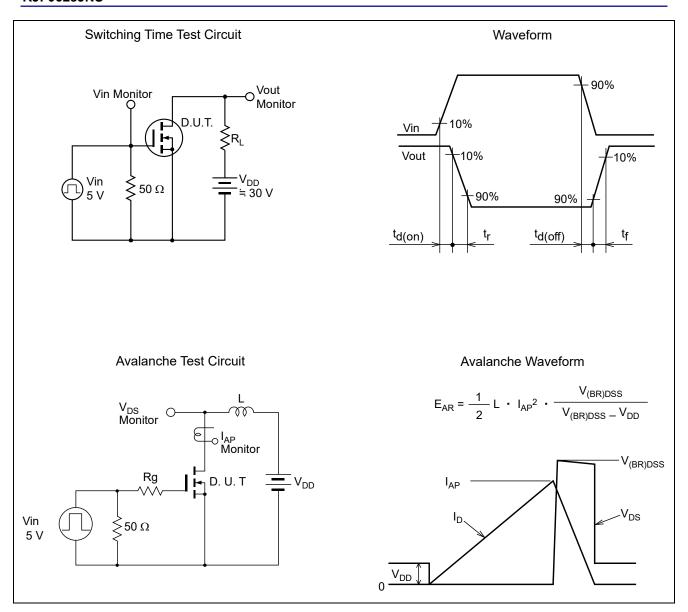
7. Including the junction temperature rise of the over loaded condition.

Main Characteristics



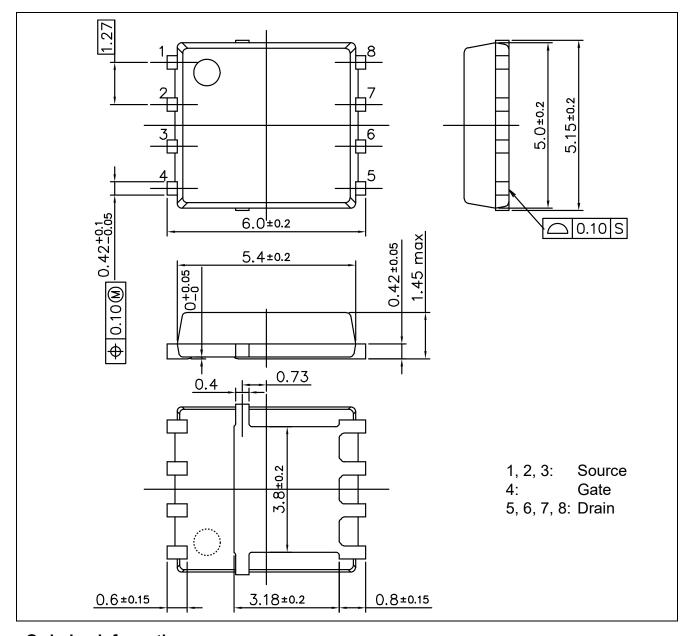






Package Dimensions

8-pin HSON Single (Mass: 0.13 g TYP.)



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJF0628JNS-00-Q7	2500 pcs/reel	Taping

Note: The symbol of 2nd "-" is occasionally presented as "#".

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